LL4001G THRU LL4007G

SURFACE MOUNT GLASS PASSIVATED SILICON RECTIFIERS

Reverse Voltage - 50 to 1000 V

Forward Current - 1 A

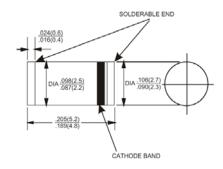
Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- High temperature metallurgically bonded construction
- Cavity-free glass passivated junction

Mechanical data

 Case: Molded plastic, MELF (DO-213AB)
 Terminals: Solder plated, solderable per MIL-STD-750, method 208 guaranteed
 Polarity: Color band denotes cathode end

• Mounting position: Any



Plastic case MELF (DO-213AB) Dimensions in inches and (millimeters)

Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Parameter | Symbols | LL4001G | LL4002G | LL4003G | LL4004G | LL4005G | LL4006G | LL4007G | Units |
|--|--------------------|---------------|---------|---------|---------|---------|---------|---------|-------|
| Maximum Recurrent Peak Reverse Voltage | V_{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS Voltage | V_{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC Blocking Voltage | V_{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum Average Forward Rectified Current at T _A = 75 °C | I _{F(AV)} | 1 | | | | | | Α | |
| Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method) | I _{FSM} | 30 | | | | | | Α | |
| Maximum Forward Voltage at 1 A | V _F | 1.1 | | | | | | V | |
| $ \begin{array}{ll} \text{Maximum Reverse Current} & \text{$T_{A} = 25 ^{\circ}\text{C}$} \\ \text{at Rated DC Blocking Voltage} & \text{$T_{A} = 125 ^{\circ}\text{C}$} \end{array} $ | I _R | 5 200 | | | | | | μA | |
| Typical Junction Capacitance 1) | CJ | 15 | | | | | | pF | |
| Typical Thermal Resistance 2) | $R_{\theta JA}$ | 50 | | | | | | °C/W | |
| Typical Thermal Resistance 3) | $R_{\theta JT}$ | 20 | | | | | | °C/W | |
| Operating Junction Temperature Range | T _j | - 55 to + 150 | | | | | | °C | |
| Storage Temperature Range | T _{stg} | - 55 to + 150 | | | | | | °C | |

¹⁾ Measured at 1 MHz and applied reverse voltage of 4 V D.C



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²⁾ Thermal resistance from junction to ambient, 0.24 X 0.24" (6 X 6 mm) copper pads to each terminal

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Fig. 1 - Forward Current Derating Curve 60Hz Resistive or Average Forward Current (A) 8.0 Inductive Load 0.6 0.4 0.2 0 L 25 50 75 100 150 Terminal Temperature (°C)

Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

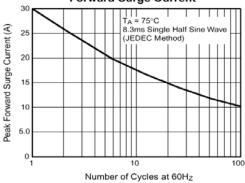


Fig. 3 - Typical Instantaneous
Forward Characteristics

10
Pulse Width = 300µs
1% Duty Cycle

7, = 25°C

1.0

Instantaneous Forward Voltage (V)

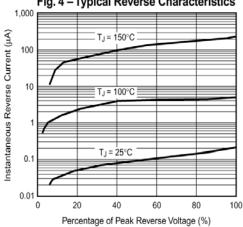
1.6

0.6

0.8

0.4

Fig. 4 - Typical Reverse Characteristics



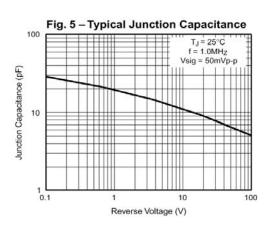
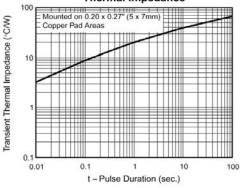


Fig. 6 - Typical Transient Thermal Impedance





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